**Vishay Semiconductors** 

# High Performance Schottky Rectifier, 20 A



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PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub> 20 A						
V <sub>R</sub>	15 V					
V <sub>F</sub> at I <sub>F</sub>	See Electrical table					
I <sub>RM</sub> max.	600 mA at 100 °C					
T <sub>J</sub> max.	125 °C					
E <sub>AS</sub>	10 mJ					
Package	TO-220AC 2L					
Circuit configuration	Single					

### FEATURES

- 125 °C T<sub>J</sub> operation ( $V_R < 5 V$ )
- Optimized for OR-ing applications
- Ultra low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Designed and qualified according to JEDEC<sup>®</sup>-JESD47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### DESCRIPTION

The Schottky rectifier module has been optimized for ultra low forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL CHARACTERISTICS VALUES UNI							
I <sub>F(AV)</sub>	Rectangular waveform	20	А				
V <sub>RRM</sub>		15	V				
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	700	А				
V <sub>F</sub>	19 A <sub>pk</sub> , T <sub>J</sub> = 125 °C (typical)	0.25	V				
TJ	Range	-55 to +125	°C				

VOLTAGE RATINGS							
PARAMETER SYMBOL VS-STPS20L15D-M3 UNITS							
Maximum DC reverse voltage	V <sub>R</sub>	15	V				
Maximum working peak reverse voltage	V <sub>RWM</sub>	15	v				

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS					
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle, $T_C = 85 \ ^\circ C$ , r	20	А					
Maximum peak one cycle non-repetitive surge current	1	5 $\mu s$ sine or 3 $\mu s$ rect. pulse	Following any rated load condition and with rated	700	A				
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	330					
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 2 A, L = 6 mH	10	mJ					
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to ze Frequency limited by T <sub>J</sub> maxin	2	А					

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# VS-STPS20L15D-M3



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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS					
Forward voltage drop See fig. 1		19 A	T.I = 25 °C	-	0.41	v		
	V <sub>FM</sub> <sup>(1)</sup>	40 A	1j=25 0	-	0.52			
	V FM (**	19 A	T.I = 125 °C	0.25	0.33			
		40 A	1j = 125 C	0.37	0.50			
Reverse leakage current	I <sub>BM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C		-	10	mA		
See fig. 2	IRM \''	T <sub>J</sub> = 100 °C	$V_R = Rated V_R$	-	600	ma		
Threshold voltage	V <sub>F(TO)</sub>			0.1	82	V		
Forward slope resistance	r <sub>t</sub>	$T_J = T_J$ maximum	7.6		mΩ			
Maximum junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal rar	-	2000	pF			
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5	8	-	nH			
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10	000	V/µs		

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction temperature range	TJ		-55 to +125	С°			
Maximum storage temperature range	T <sub>Stg</sub>		-55 to +150				
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation See fig. 4					
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth and greased (for TO-220)	0.50				
Maximum thermal resistance, junction to ambient	R <sub>thJA</sub>	DC operation (for D <sup>2</sup> PAK)	40				
Approvimate weight			2	g			
Approximate weight			0.07	oz.			
Mounting torque		Non-lubricated threads	6 (5)	kgf ⋅ cm			
Mounting torque maximum		Non-Iudiicaleu lineaus	12 (10)	(lbf ⋅ in)			
Marking device		Case style TO-220AC 2L	STPS20L15D				



VS-STPS20L15D-M3

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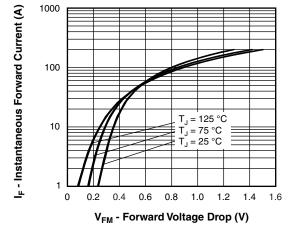


Fig. 1 - Maximum Forward Voltage Drop Characteristics

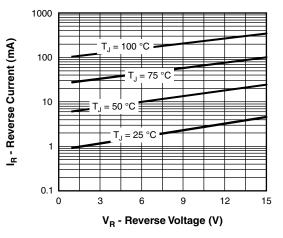


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

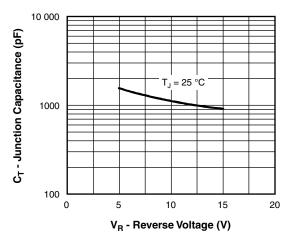


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

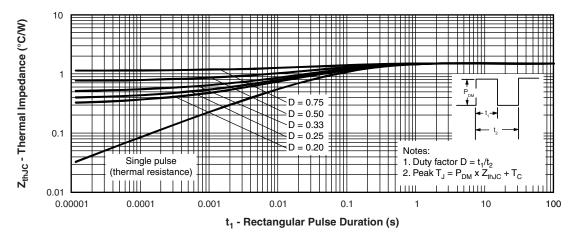
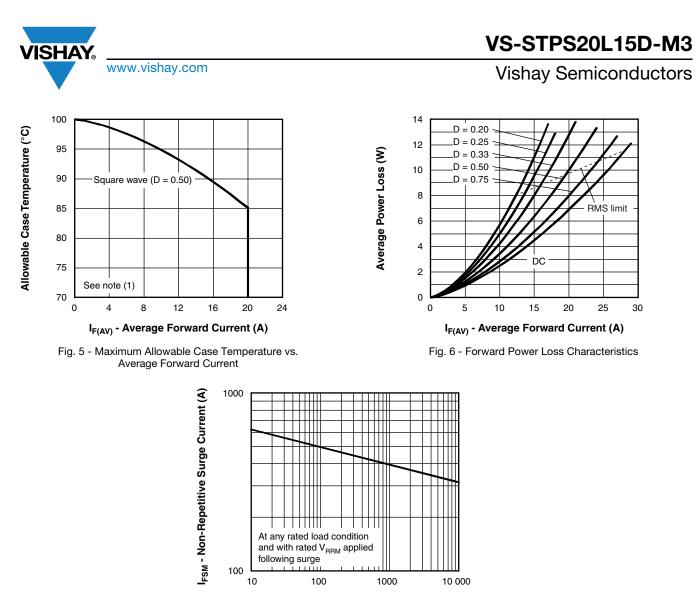


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

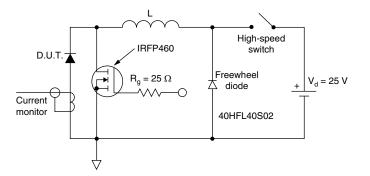
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t<sub>p</sub> - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current





#### Note

- <sup>(1)</sup> Formula used:  $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$ ;
- $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ \mathsf{x} \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ \mathsf{x} \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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Device

### **ORDERING INFORMATION TABLE**

code	vs-	STPS	20	L	15	D	-M3
	1	2	3	4	5	6	7
	1 -	Vish	ay Sem	niconduc	tors pro	duct	
	2 -	Sch	ottky ST	PS seri	es		
	3 -	Curi	rent ratii	ng (20 =	20 A)		
	4 -	L =	Low vol	tage dro	р		
	5 -	Volt	age ratii	ng (15 =	15 V)		
	6 -	D =	Essenti	al part n	umber		
	7 -	Env	ironmer	ntal digit			
		-M3	- haloc	non_froo	PoHS-	complia	at and t

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N BASE QUANTITY PACKAGING DESCRIPTION							
VS-STPS20L15D-M3	50	Antistatic plastic tubes					

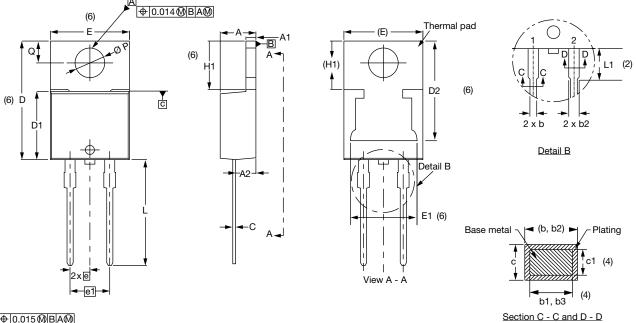
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?96156			
Part marking information	www.vishay.com/doc?95391			
SPICE model	www.vishay.com/doc?95305			



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# **TO-220AC 2L**

### **DIMENSIONS** in millimeters and inches



⊕0.015@BA@



SYMBOL	MILLIMETERS		INCHES		NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

SYMBOL	MILLIN	IETERS	INCHES		NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	13.30	0.460	0.524	6, 7
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

Conforms to JEDEC<sup>®</sup> outline TO-220AC

#### Notes

<sup>(2)</sup> Lead dimension and finish uncontrolled in L1

(4) Dimension b1, b3, and c1 apply to base metal only

- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- <sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> TO-220, except D2

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 $<sup>^{(1)}\,</sup>$  Dimensioning and tolerancing as per ASME Y14.5M-1994  $\,$ 

<sup>&</sup>lt;sup>(3)</sup> Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

<sup>&</sup>lt;sup>(5)</sup> Controlling dimensions: inches



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